

CAT24AA01, CAT24AA02

EEPROM Serial 1/2-Kb I²C

Description

The CAT24AA01/24AA02 are EEPROM Serial 1/2-Kb I²C devices internally organized as 128x8/256x8 bits.

They feature a 16-byte page write buffer and support the Standard (100 kHz), Fast (400 kHz) and Fast-Plus (1 MHz) I²C protocols.

In contrast to the CAT24C01/24C02, the CAT24AA01/24AA02 have no external address pins, and are therefore suitable in applications that require a single CAT24AA01/02 on the I²C bus.

Features

- Supports Standard, Fast and Fast-Plus I²C Protocol
- 1.7 V to 5.5 V Supply Voltage Range
- 16-Byte Page Write Buffer
- Hardware Write Protection for Entire Memory
- Schmitt Triggers and Noise Suppression Filters on I²C Bus Inputs (SCL and SDA)
- Low Power CMOS Technology
- 1,000,000 Program/Erase Cycles
- 100 Year Data Retention
- Industrial Temperature Range
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

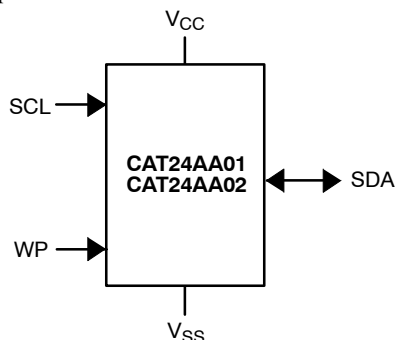


Figure 1. Functional Symbol



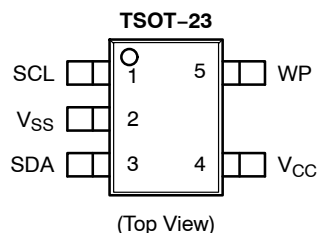
ON Semiconductor®

www.onsemi.com

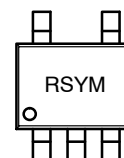


TSOT-23
TD SUFFIX
CASE 419AE

PIN CONFIGURATIONS



MARKING DIAGRAM



RS = Device Code
Y = Production Year (Last Digit)
M = Production Month (1-9, O, N, D)

PIN FUNCTION

| Pin Name | Function |
|-----------------|---------------------|
| SDA | Serial Data/Address |
| SCL | Clock Input |
| WP | Write Protect |
| V _{CC} | Power Supply |
| V _{SS} | Ground |

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 8 of this data sheet.

CAT24AA01, CAT24AA02

Table 1. ABSOLUTE MAXIMUM RATINGS

| Parameters | Ratings | Units |
|--|--------------|-------|
| Storage Temperature | -65 to +150 | °C |
| Voltage on any Pin with Respect to Ground (Note 1) | -0.5 to +6.5 | V |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. The DC input voltage on any pin should not be lower than -0.5 V or higher than $V_{CC} + 0.5$ V. During transitions, the voltage on any pin may undershoot to no less than -1.5 V or overshoot to no more than $V_{CC} + 1.5$ V, for periods of less than 20 ns.

Table 2. REABILITY CHARACTERISTICS (Note 2)

| Symbol | Parameter | Min | Units |
|--------------------|----------------|-----------|----------------------|
| N_{END} (Note 3) | Endurance | 1,000,000 | Program/Erase Cycles |
| T_{DR} | Data Retention | 100 | Years |

2. These parameters are tested initially and after a design or process change that affects the parameter according to appropriate AEC-Q100 and JEDEC test methods.
3. Page Mode @ 25°C

Table 3. D.C. OPERATING CHARACTERISTICS ($V_{CC} = 1.7$ V to 5.5 V, $T_A = -40^\circ\text{C}$ to 85°C , unless otherwise specified.)

| Symbol | Parameter | Test Conditions | Min | Max | Units |
|-----------|--------------------|--|---------------------|---------------------|---------------|
| I_{CCR} | Read Current | Read, $f_{SCL} = 400$ kHz | | 0.5 | mA |
| I_{CCW} | Write Current | Write | | 1 | mA |
| I_{SB} | Standby Current | All I/O Pins at GND or V_{CC} | | 1 | μA |
| I_L | I/O Pin Leakage | Pin at GND or V_{CC} | | 1 | μA |
| V_{IL} | Input Low Voltage | | -0.5 | $V_{CC} \times 0.3$ | V |
| V_{IH} | Input High Voltage | | $V_{CC} \times 0.7$ | $V_{CC} + 0.5$ | V |
| V_{OL1} | Output Low Voltage | $V_{CC} \geq 2.5$ V, $I_{OL} = 3.0$ mA | | 0.4 | V |
| V_{OL2} | Output Low Voltage | $V_{CC} < 2.5$ V, $I_{OL} = 1.0$ mA | | 0.2 | V |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Table 4. PIN IMPEDANCE CHARACTERISTICS ($V_{CC} = 1.7$ V to 5.5 V, $T_A = -40^\circ\text{C}$ to 85°C , unless otherwise specified.)

| Symbol | Parameter | Conditions | Max | Units |
|-------------------|--------------------------------|-------------------|-----|---------------|
| C_{IN} (Note 2) | SDA I/O Pin Capacitance | $V_{IN} = 0$ V | 8 | pF |
| C_{IN} (Note 2) | Input Capacitance (other pins) | $V_{IN} = 0$ V | 6 | pF |
| I_{WP} (Note 4) | WP Input Current | $V_{IN} < V_{IH}$ | 100 | μA |
| | | $V_{IN} > V_{IH}$ | 1 | |

4. When not driven, the WP pin is pulled down to GND internally. For improved noise immunity, the internal pull-down is relatively strong; therefore the external driver must be able to supply the pull-down current when attempting to drive the input HIGH. To conserve power, as the input level exceeds the trip point of the CMOS input buffer ($\sim 0.5 \times V_{CC}$), the strong pull-down reverts to a weak current source.

CAT24AA01, CAT24AA02

Table 5. A.C. CHARACTERISTICS (Note 5) ($V_{CC} = 1.7\text{ V}$ to 5.5 V , $T_A = -40^\circ\text{C}$ to 85°C , unless otherwise specified.)

| Symbol | Parameter | Standard $V_{CC} = 1.7\text{ V} - 5.5\text{ V}$ | | Fast $V_{CC} = 1.7\text{ V} - 5.5\text{ V}$ | | 1 MHz $V_{CC} = 2.5\text{ V} - 5.5\text{ V}$ | | Units |
|--------------------------|--|--|------|--|-----|---|------|---------------|
| | | Min | Max | Min | Max | Min | Max | |
| F_{SCL} | Clock Frequency | | 100 | | 400 | | 1000 | kHz |
| $t_{HD:STA}$ | START Condition Hold Time | 4 | | 0.6 | | 0.25 | | μs |
| t_{LOW} | Low Period of SCL Clock | 4.7 | | 1.3 | | 0.5 | | μs |
| t_{HIGH} | High Period of SCL Clock | 4 | | 0.6 | | 0.5 | | μs |
| $t_{SU:STA}$ | START Condition Setup Time | 4.7 | | 0.6 | | 0.25 | | μs |
| $t_{HD:DAT}$ | Data In Hold Time | 0 | | 0 | | 0 | | ns |
| $t_{SU:DAT}$ | Data In Setup Time | 250 | | 100 | | 100 | | ns |
| t_R (Note 6) | SDA and SCL Rise Time | | 1000 | | 300 | | 300 | ns |
| t_F (Note 6) | SDA and SCL Fall Time | | 300 | | 300 | | 100 | ns |
| $t_{SU:STO}$ | STOP Condition Setup Time | 4 | | 0.6 | | 0.25 | | μs |
| t_{BUF} | Bus Free Time Between STOP and START | 4.7 | | 1.3 | | 0.5 | | μs |
| t_{AA} | SCL Low to Data Out Valid | | 3.5 | | 0.9 | | 0.4 | μs |
| t_{DH} | Data Out Hold Time | 100 | | 50 | | 50 | | ns |
| T_i (Note 6) | Noise Pulse Filtered at SCL and SDA Inputs | | 100 | | 100 | | 100 | ns |
| $t_{SU:WP}$ | WP Setup Time | 0 | | 0 | | 0 | | μs |
| $t_{HD:WP}$ | WP Hold Time | 2.5 | | 2.5 | | 1 | | μs |
| t_{WR} | Write Cycle Time | | 5 | | 5 | | 5 | ms |
| t_{PU} (Notes 6, 7) | Power-up to Ready Mode | | 1 | | 1 | | 1 | ms |

5. Test conditions according to "A.C. Test Conditions" table.

6. Tested initially and after a design or process change that affects this parameter.

7. t_{PU} is the delay between the time V_{CC} is stable and the device is ready to accept commands.

Table 6. A.C. TEST CONDITIONS

| | |
|---------------------------|--|
| Input Levels | $0.2 \times V_{CC}$ to $0.8 \times V_{CC}$ |
| Input Rise and Fall Times | $\leq 50\text{ ns}$ |
| Input Reference Levels | $0.3 \times V_{CC}$, $0.7 \times V_{CC}$ |
| Output Reference Levels | $0.5 \times V_{CC}$ |
| Output Load | Current Source: $I_{OL} = 3\text{ mA}$ ($V_{CC} \geq 2.5\text{ V}$); $I_{OL} = 1\text{ mA}$ ($V_{CC} < 2.5\text{ V}$); $C_L = 100\text{ pF}$ |

CAT24AA01, CAT24AA02

Power-On Reset (POR)

Each CAT24AA01/02 incorporates Power-On Reset (POR) circuitry which protects the internal logic against powering up in the wrong state. The device will power up into Standby mode after V_{CC} exceeds the POR trigger level and will power down into Reset mode when V_{CC} drops below the POR trigger level.

This bi-directional POR behavior protects the device against brown-out failure, following a temporary loss of power.

Pin Description

SCL: The Serial Clock input pin accepts the clock signal generated by the Master.

SDA: The Serial Data I/O pin accepts input data and delivers output data. In transmit mode, this pin is open drain. Data is acquired on the positive edge, and delivered on the negative edge of SCL.

WP: When the Write Protect input pin is forced HIGH by an external source, all write operations are inhibited. When the pin is not driven by an external source, it is pulled LOW internally.

Functional Description

The CAT24AA01/02 supports the Inter-Integrated Circuit (I²C) Bus protocol. The protocol relies on the use of a Master device, which provides the clock and directs bus traffic, and Slave devices which execute requests. The CAT24AA01/02 operates as a Slave device. Both Master and Slave can transmit or receive, but only the Master can assign those roles.

I²C BUS PROTOCOL

The 2-wire I²C bus consists of two lines, SCL and SDA, connected to the V_{CC} supply via pull-up resistors. The Master provides the clock to the SCL line, and the Master and Slaves drive the SDA line. A '0' is transmitted by pulling a line LOW and a '1' by releasing it HIGH. Data transfer may be initiated only when the bus is not busy (see A.C. Characteristics). During data transfer, SDA must remain stable while SCL is HIGH.

START/STOP Condition

An SDA transition while SCL is HIGH creates a START or STOP condition (Figure 2). A START is generated by a HIGH to LOW transition, while a STOP is generated by a LOW to HIGH transition. The START acts like a wake-up call. Absent a START, no Slave will respond to the Master. The STOP completes all commands.

Device Addressing

The Master addresses a Slave by creating a START condition and then broadcasting an 8-bit Slave address (Figure 3). The four most significant bits of the Slave address are 1010 (Ah).

For the CAT24AA01/02 the next three bits must be 000.

The last bit, R/\overline{W} , instructs the Slave to either provide (1) or accept (0) data, i.e. it signals a Read (1) or a Write (0) request.

Acknowledge

During the 9th clock cycle following every byte sent onto the bus, the transmitter releases the SDA line, allowing the receiver to respond. The receiver then either acknowledges (ACK) by pulling SDA LOW, or does not acknowledge (NoACK) by letting SDA stay HIGH (Figure 4). Bus timing is illustrated in Figure 5.

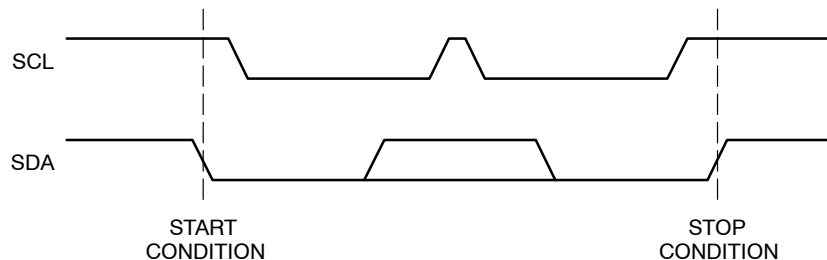


Figure 2. Start/Stop Timing

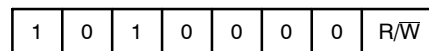


Figure 3. Slave Address Bits

CAT24AA01, CAT24AA02

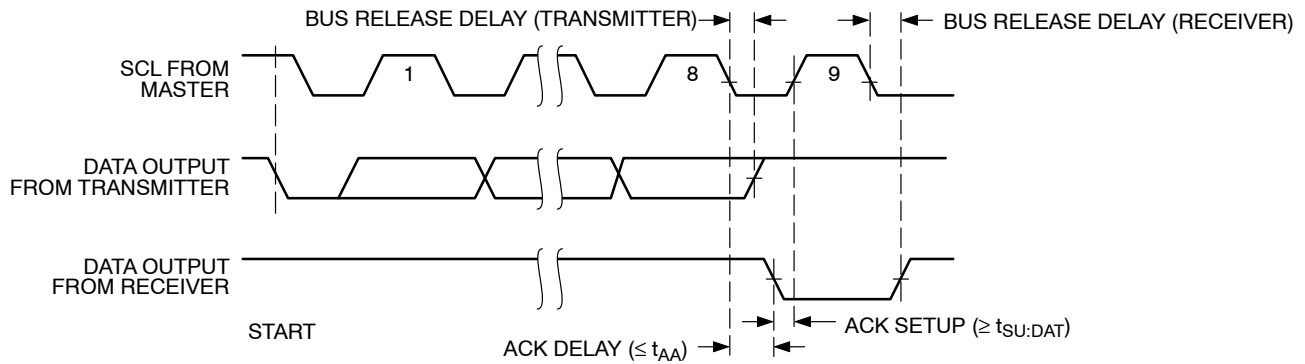


Figure 4. Acknowledge Timing

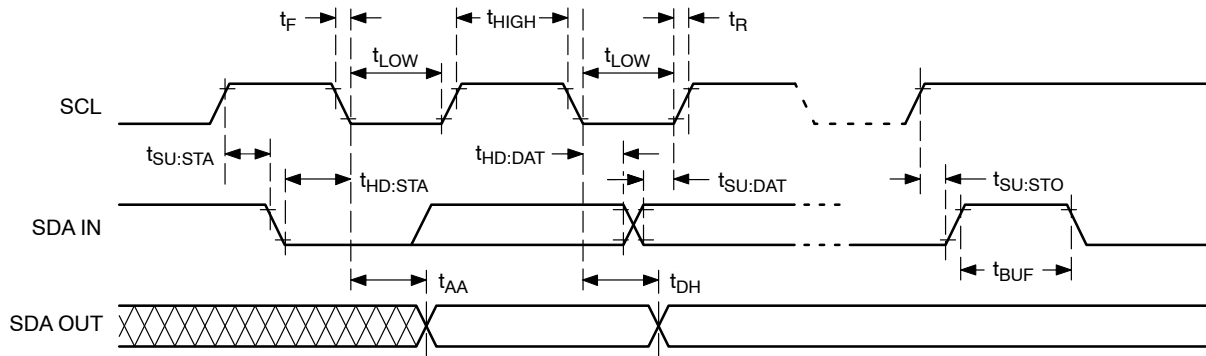


Figure 5. Bus Timing

WRITE OPERATIONS

Byte Write

To write data to memory, the Master creates a START condition on the bus and then broadcasts a Slave address with the R/\overline{W} bit set to '0'. The Master then sends an address byte and a data byte and concludes the session by creating a STOP condition on the bus. The Slave responds with ACK after every byte sent by the Master (Figure 5). The STOP starts the internal Write cycle, and while this operation is in progress (t_{WR}), the SDA output is tri-stated and the Slave does not acknowledge the Master (Figure 6).

Page Write

The Byte Write operation can be expanded to Page Write, by sending more than one data byte to the Slave before issuing the STOP condition (Figure 7). Up to 16 distinct data bytes can be loaded into the internal Page Write Buffer starting at the address provided by the Master. The page address is latched, and as long as the Master keeps sending data, the internal byte address is incremented up to the end of page, where it then wraps around (within the page). New data can therefore replace data loaded earlier. Following the STOP, data loaded during the Page Write session will be written to memory in a single internal Write cycle (t_{WR}).

Acknowledge Polling

As soon (and as long) as internal Write is in progress, the Slave will not acknowledge the Master. This feature enables the Master to immediately follow-up with a new Read or Write request, rather than wait for the maximum specified Write time (t_{WR}) to elapse. Upon receiving a NoACK response from the Slave, the Master simply repeats the request until the Slave responds with ACK.

Hardware Write Protection

With the WP pin held HIGH, the entire memory is protected against Write operations. If the WP pin is left floating or is grounded, it has no impact on the Write operation. The state of the WP pin is strobed on the last falling edge of SCL immediately preceding the 1st data byte (Figure 8). If the WP pin is HIGH during the strobe interval, the Slave will not acknowledge the data byte and the Write request will be rejected.

Delivery State

The CAT24AA01/02 is shipped erased, i.e., all bytes are FFh.

CAT24AA01, CAT24AA02

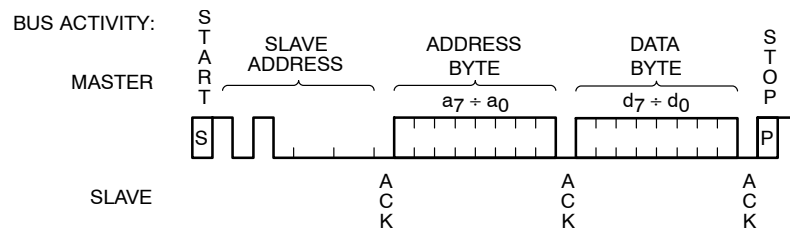


Figure 6. Byte Write Sequence

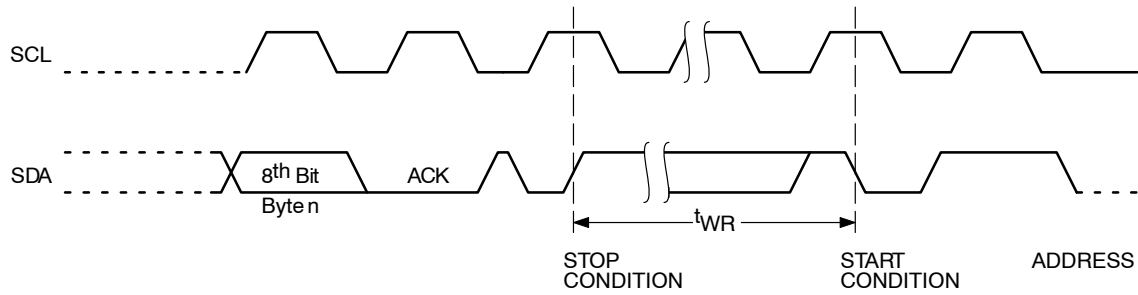


Figure 7. Write Cycle Timing

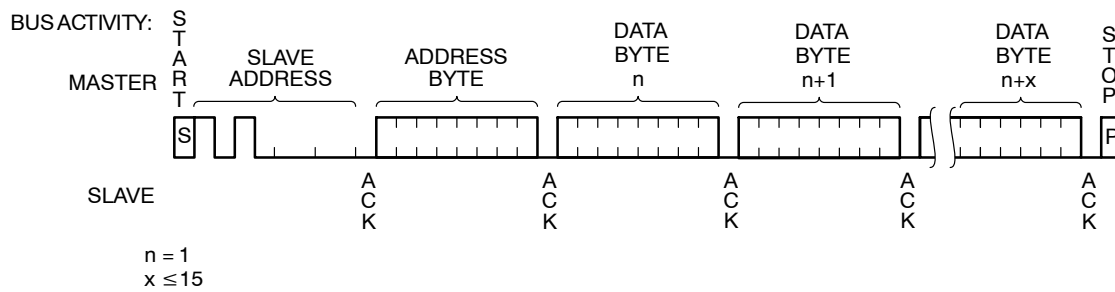


Figure 8. Page Write Sequence

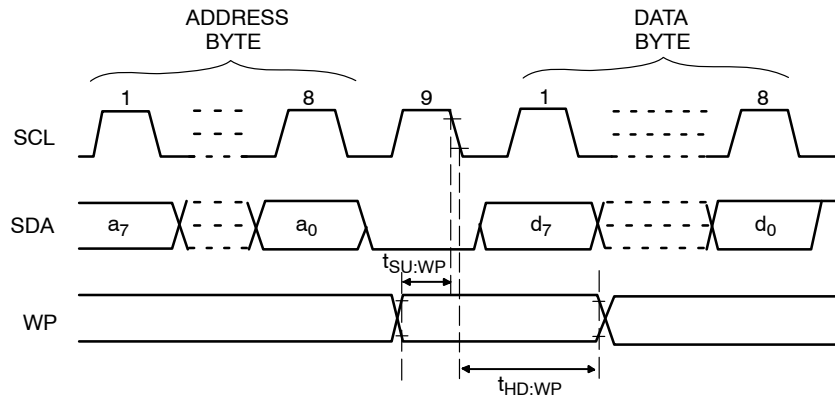


Figure 9. WP Timing

READ OPERATIONS

Immediate Read

To read data from memory, the Master creates a START condition on the bus and then broadcasts a Slave address with the R/\overline{W} bit set to '1'. The Slave responds with ACK and starts shifting out data residing at the current address. After receiving the data, the Master responds with NoACK and terminates the session by creating a STOP condition on the bus (Figure 10). The Slave then returns to Standby mode.

Selective Read

To read data residing at a specific address, the selected address must first be loaded into the internal address register. This is done by starting a Byte Write sequence, whereby the Master creates a START condition, then broadcasts a Slave address with the R/\overline{W} bit set to '0' and then sends an address byte to the Slave. Rather than completing the Byte Write sequence by sending data, the Master then creates a START

condition and broadcasts a Slave address with the R/\overline{W} bit set to '1'. The Slave responds with ACK after every byte sent by the Master and then sends out data residing at the selected address. After receiving the data, the Master responds with NoACK and then terminates the session by creating a STOP condition on the bus (Figure 11).

Sequential Read

If, after receiving data sent by the Slave, the Master responds with ACK, then the Slave will continue transmitting until the Master responds with NoACK followed by STOP (Figure 12). During Sequential Read the internal byte address is automatically incremented up to the end of memory, where it then wraps around to the beginning of memory. For the CAT24AA01, the internal address counter will not wrap around at the end of the 128 byte memory space.

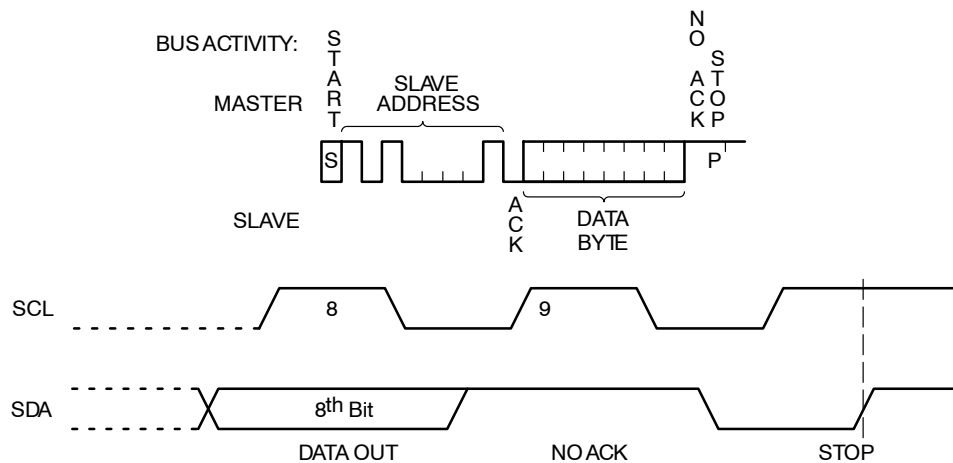


Figure 10. Immediate Read Sequence and Timing

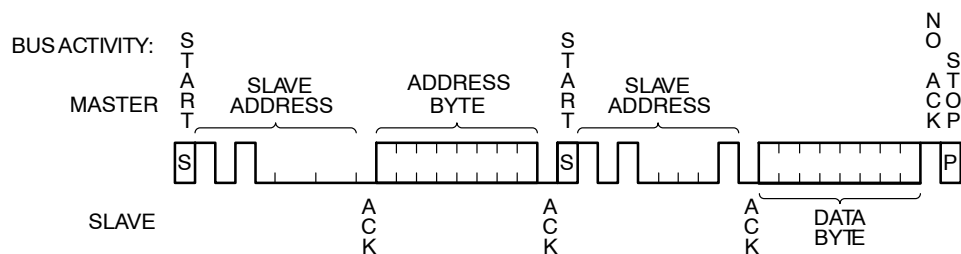


Figure 11. Selective Read Sequence

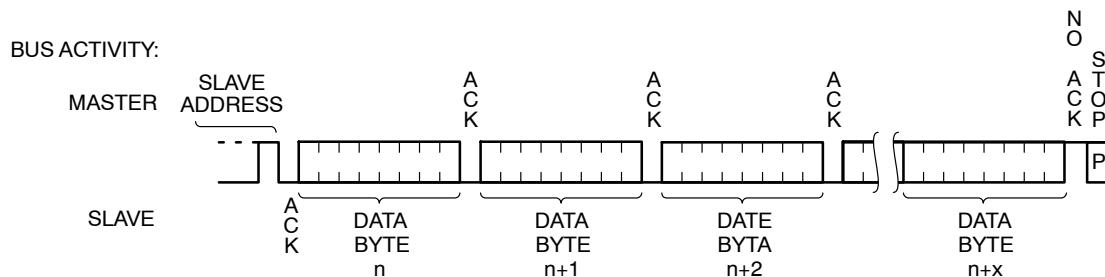


Figure 12. Sequential Read Sequence

CAT24AA01, CAT24AA02

Ordering Information

| Device Order Number | Specific Device Marking | Package Type | Temperature Range | Lead Finish | Shipping [†] |
|---------------------|-------------------------|--------------|------------------------------------|-------------|------------------------------------|
| CAT24AA01TDI-GT3 | RS | SOT-23-5 | I = Industrial (-40°C to +85°C) | NiPdAu | Tape & Reel, 3,000 Units / Reel |
| CAT24AA02TDI-GT3 | RS | SOT-23-5 | I = Industrial (-40°C to +85°C) | NiPdAu | Tape & Reel, 3,000 Units / Reel |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

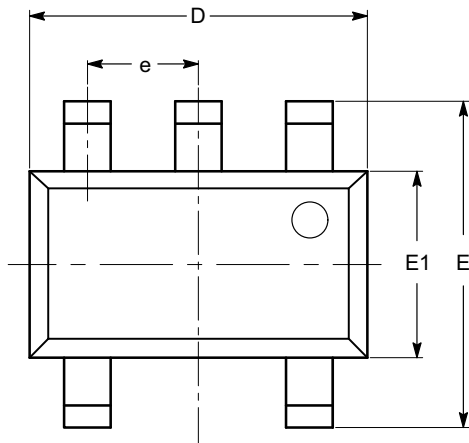
8. All packages are RoHS-compliant (Lead-free, Halogen-free).

9. The standard lead finish is NiPdAu.

10. For additional package and temperature options, please contact your nearest ON Semiconductor sales office.

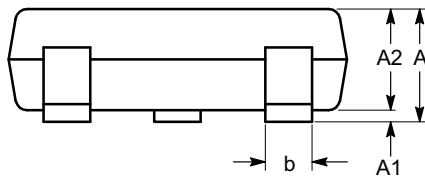
TSOT-23, 5 LEAD
CASE 419AE-01
ISSUE O

DATE 19 DEC 2008

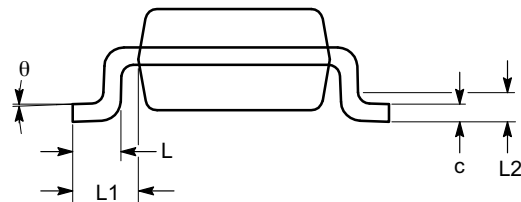


TOP VIEW

| SYMBOL | MIN | NOM | MAX |
|--------|----------|------|------|
| A | | | 1.00 |
| A1 | 0.01 | 0.05 | 0.10 |
| A2 | 0.80 | 0.87 | 0.90 |
| b | 0.30 | | 0.45 |
| c | 0.12 | 0.15 | 0.20 |
| D | 2.90 BSC | | |
| E | 2.80 BSC | | |
| E1 | 1.60 BSC | | |
| e | 0.95 TYP | | |
| L | 0.30 | 0.40 | 0.50 |
| L1 | 0.60 REF | | |
| L2 | 0.25 BSC | | |
| θ | 0° | | 8° |



SIDE VIEW





END VIEW

Notes:

- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC MO-193.

| | | |
|-------------------------|------------------------|---|
| DOCUMENT NUMBER: | 98AON34392E | Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. |
| DESCRIPTION: | TSOT-23, 5 LEAD | PAGE 1 OF 1 |

ON Semiconductor and  are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

ON Semiconductor and  are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Email Requests to: orderlit@onsemi.com

ON Semiconductor Website: www.onsemi.com

TECHNICAL SUPPORT

North American Technical Support:

Voice Mail: 1 800-282-9855 Toll Free USA/Canada

Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative